DEVELOPING

2SC5814, 2SC5815, 2SC5816, 2SC5817

For Low Frequency Amplify Application
Silicon NPN Epitaxial Type

DESCRIPTION

2SC5814 , 2SC5815 , 2SC5816 , 2SC5817 is a super mini package silicon NPN epitaxial type transistor. It is designed for low frequency voltage amplify application.

FEATURE

Facilitates miniaturization and high-density mounting

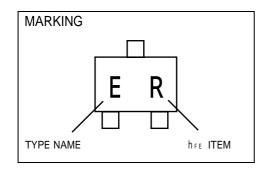
Excellent linearity of DC forward current gain

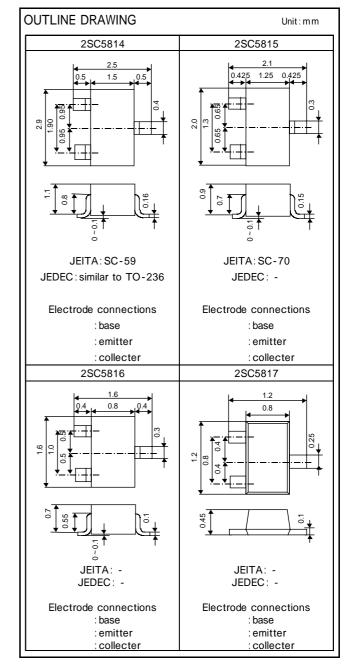
Low collecter to emitter saturation voltage

VCE(sat)=0.3V max (@IC=30mA,IB=1.5mA)

APPLICATION

For hybrid IC , small type machine low frequency voltage amplify application





MAXIMUM RATINGS (Ta=25)

SYMBOL	PARAMETER	RATINGS				UNIT
		2SC5814	2SC5815	2SC5816	2SC5817	JUNIT
V _{CBO}	Collector to Base voltage	60			V	
V _{EBO}	Emitter to Base voltage	6			V	
V _{CEO}	Collector to Emitter voltage	60			V	
I _C	Collector current	125			mA	
P _C	Collector dissipation	15	50	125	100	mW
T _j	Junction temperature	+ 125				
T _{stg}	Storage temperature	-55 ~ + 125				

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ELECTRICAL CHARACTERISTICS (Ta=25

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{(BR)CEO}	C to E break down voltage	I _C =100uA , R _{BE} =	60			V
I _{CBO}	Collector cut off current	V_{CB} =60V , I $_{E}$ =0mA			0.5	μA
Ієво	Emitter cut off current	V _{EB} =4V , I c=0mA			0.5	μA
hfE *	DC forward current gain	Vce=6V , Ic=1mA	120		560	-
hfE	DC forward current gain	Vce=6V , Ic=0.1mA	70			-
V _{CE(sat)}	C to E saturation voltage	Ic=30mA , I _B =1.5mA			0.3	V
f⊤	Gain band width product	Vce=6V , Ie=-10mA		200		MHz
Cob	Collector output capacitance	Vcb=6V , IE=0mA , f=1MHz		1.5		pF

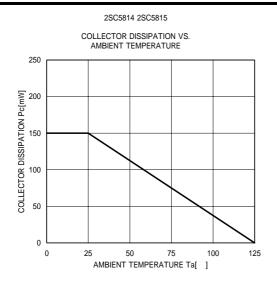
^{*} It shows h_{FE} classification in right table.

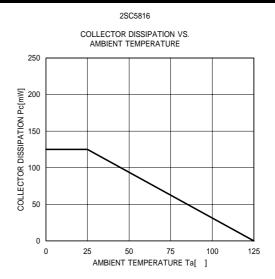
Item	Q	R	S
h _{FE}	120 ~ 270	180 ~ 390	270 ~ 560
Marking	EQ	ER	ES

Item	Е	F
h _{FE}	150 ~ 300	250 ~ 500
Marking	EE	EF

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2SC5817

COLLECTOR DISSIPATION VS.
AMBIENT TEMPERATURE

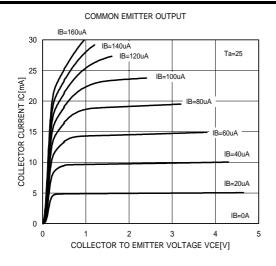
200

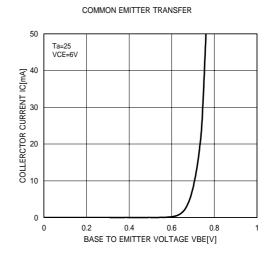
0
25
50
75
100
12

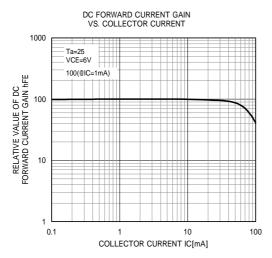
AMBIENT TEMPERATURE Ta[]

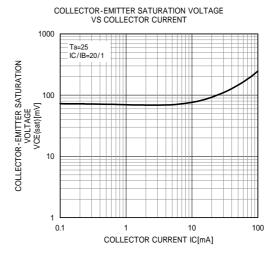
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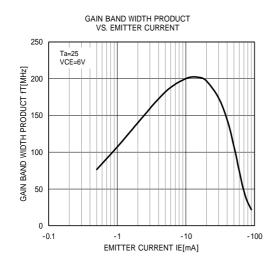
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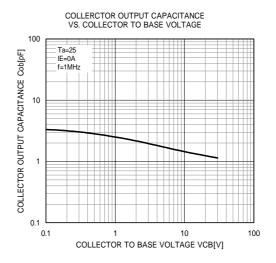














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